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(54) Title: METHOD FOR DETERMINISTIC FINISHING OF A CHUCK SURFACE

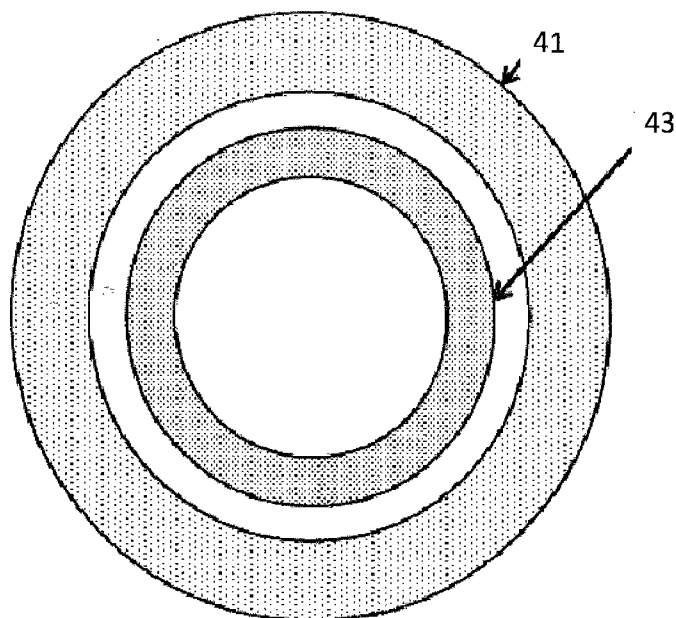


Fig. 4

(57) Abstract: In a deterministic setting for finishing the support surface of a chuck such as a wafer chuck, the treatment tool may have a contacting surface shaped as a ring, annulus, or toroid, or at least such will be the form of contact when the treatment tool is brought into contact with a flat surface. The treatment tool may have about the same hardness as the work piece (e.g., the wafer chuck) that is being finished. In one embodiment, the treatment tool, or at least the flat contacting surface, is made from silicon carbide (SiC), or contains SiC, for example, in the form of a composite material such as reaction-bonded SiC.



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## TITLE

**Method for deterministic finishing of a chuck surface**

## CROSS-REFERENCE TO RELATED APPLICATION(S)

[0001] This patent document claims the benefit of United States Provisional Patent Application No. 62/205,643, entitled "Method for deterministic finishing of a chuck surface", filed on August 14, 2015 in the name of inventor Edward Gratrix. Where permitted, the entire contents of this provisional patent application are incorporated by reference herein.

## STATEMENT REGARDING U.S. FEDERALLY SPONSORED RESEARCH

[0002] None.

## TECHNICAL FIELD

[0003] The present invention relates to the use of a unique treatment tool in a deterministic manner for grinding, lapping, polishing or roughening the surface of a work piece such as a chuck for supporting semiconductor wafers.

## BACKGROUND ART

[0004] Chucks, such as pin chucks, are used to hold flat components for processing. The most common use is to hold wafers (Si, SiC, GaAs, GaN, Sapphire, other) during processing to yield a semiconductor device. Other uses include holding substrates during the fabrication of flat panel displays, solar cells and other such manufactured products. These chucking components are known by many names, including wafer chucks, wafer tables, wafer handling devices, etc.

[0005] The use of pins on these devices is to provide minimum chuck-to-substrate contact. Minimum contact reduces contamination and enhances the ability to maintain high flatness. The pin tops need to have low wear in use to maximize life and precision. The pin tops also need to possess low friction so the substrate easily slides on and off, and lies flat on the pins.

[0006] A pin chuck consists of a rigid body with a plurality of pins on the surface on which the substrate to be processed (e.g., Si wafer) rests. The pins exist in many geometries, and go by many names including burls, mesas, bumps, proud lands, proud rings, etc.

[0007] Regardless of whether the chuck is of the “pin” type or not, the surface that supports whatever is to be chucked (e.g., a semiconductor wafer) needs to be flat to a very high degree of precision. In the case of semiconductor lithography, the flatness is measured in nanometers (nm).

[0008] Methods of flattening are often limited by the flatness of the equipment used such as a flat lap or over arm configuration. With harder and harder materials like ceramics, and in particular SiC and reaction bonded SiC (sometimes referred to here as “RBSC” or “RBSiC”), the uniformity of the lap conditions tend to dominate the cause for non uniformity. These conditions are properties like media, swarf (e.g., contamination or debris), velocity and pressure distribution.

[0009] There are common techniques to deterministically correct for the errors by using a smaller tool and generating a mathematical “hit” map to locally remove more or less material. Some techniques for this deterministic correction include, but not limited to, Ion Beam Figuring (IBF), Magneto Rheological

Finishing (MRF), and computer controlled polishing (CCP). As used herein, the phrase “deterministic correction” means that figure, elevation or roughness data as measured for example, by an interferometer or profilometer, is fed into a finishing machine such as a lapping machine, and the machine processes only those areas of the work piece that are in error and need processing (e.g., grinding, lapping or texturing). The machine does not automatically treat the entire surface of the work piece.

[0010] For tools, particularly used in semiconductor handling, the flatness is critical; however, unlike optical surfaces, which require control of a wide range of spatial frequencies, these applications require control over only a narrow range of spatial frequencies.

[0011] The issue with using known deterministic techniques is the tool size is often fixed over a narrow range of spatial frequencies ( $<10\text{mm}$ ), and the tool needs to be traversed over a substantially large substrate ( $450\text{mm}$ ), thus consuming massive amounts of processing and machining time.

[0012] The instant invention addresses these issues, and provides a solution.

## DISCLOSURE OF THE INVENTION

[0013] In a deterministic setting for finishing the support surface of a chuck such as a wafer chuck, the treatment tool may have a contacting surface configured such that when this contacting or treatment surface is brought into contact with a flat surface, for example, of that of a wafer chuck, the area of contact may be in the form of a circle, ring, or annulus. Thus, the contacting surface of the treatment tool may be slightly toroid-shaped, even though it may appear flat using a mere visual inspection. The treatment tool may have about

the same hardness as the work piece (e.g., the wafer chuck) that is being finished. In one embodiment, the treatment tool, or at least the contacting surface, is made from silicon carbide (SiC), or contains SiC, for example, in the form of a composite material such as reaction-bonded SiC.

**[0014]** Embodiments of the instant invention provide for a method for finishing the support surface of a chuck, comprising:

(a) providing a machine comprising a treatment tool comprising an operating or contacting surface of uniform elevation, and shaped such that when the contacting surface of the treatment tool is brought into contact with a flat surface, the area of contact is in the form of a circle, ring or annulus;

(b) providing information to said machine concerning one or more regions on the support surface that require correction;

(c ) physically or mechanically contacting said operating surface of said treatment tool to said support surface; and

(d) moving said treatment tool at an applied pressure over at least a portion of said chuck support surface to be finished, whereby said machine uses said inputted information to treat substantially only those regions of said support surface that require correction;

(e) and wherein a diameter of said support surface is larger than a diameter of said annulus.

**[0015]** Other embodiments of the instant invention provide for a method for finishing the support surface of a chuck, comprising:

(a) providing a plurality of treatment tools each comprising a flat surface configured to contact and pass over said support surface;

(b) contacting said flat surface of each of said treatment tools to said support surface; and

(c ) simultaneously moving at least two of said plurality of treatment tools at an applied pressure over at least a portion of said chuck support surface to be finished;

(d) wherein said applied pressure of each of said plurality against said support surface is independent of that of the others of said plurality, and controllable;

(e) and further wherein a diameter of said support surface is larger than an effective diameter of said plurality.

### BRIEF DESCRIPTION OF THE DRAWINGS

[0016] Figure 1 is a power spectral density plot showing the reduction in amplitude of the spatial frequencies nominally associated with an annular tool of 18mm diameter.

[0017] Figure 2: This figure shows a typical part with global curvature in predominately the form of a sphere and saddle shape. These are the features that need to be eliminated.

[0018] Figure 3: This shows the same part as in Figure 2 with a low spatial frequency removed. This region is where some applications are the most sensitive.

[0019] Figure 4: Diagram showing concentric tools of different diameter, each independently configured with pressure to float over surface to fulfill a specific function: shape, flatten or roughen for example.

**[0020]** Figure 5: An option showing a cluster of two or more tools that are non-concentric performing independent actions of shaping of different spatial frequency ranges or texturing (roughening/smoothing). Rotation of the cluster allows the action to appear as one larger tool head with a designed function by the sum of the independent members of the cluster. All tools are free to float on the surface.

**[0021]** Figures 6A and 6B are optical photomicrographs of a ground and polished reaction bonded silicon carbide flat surface before and after treatment with a tool operated in “surface roughening” mode.

#### MODES FOR CARRYING OUT THE INVENTION

**[0022]** In a first aspect of the invention, a novel treatment tool is used in a deterministic manner to process (e.g., grind, lap, polish, roughen or clean) a work piece such as the support surface of a wafer chuck. The treatment tool features a surface of uniform elevation configured to contact and abrade the surface of the work piece as the treatment tool passes over it. The treatment tool may have about the same hardness as the work piece. Visually, the treatment tool may have the appearance of a disc. Alternatively, it may appear as an annulus, ring or toroid. If shaped as an annulus or ring or toroid, the space inside or within the annular space may contain a second treatment tool. Further, the treatment tool may feature a plurality of rings or toroids gathered or assembled together, and collectively defining a common flat surface.

**[0023]** In one embodiment, the treatment tool is 27 mm in diameter. Visually, the contact surface appears to be a flat disc, but in reality it has a slight toroidal shape so that when it is brought into contact with the flat surface, the area of contact is not that of a disc but instead is a circle or annulus.



**[0024]** The same treatment tool may be used in cleaning, profiling and roughening modes, depending upon how the tool is used. For example, given a 27mm diameter tool fabricated from reaction bonded silicon carbide, for cleaning debris off of a wafer chuck of similar hardness, a dead weight loading of 5-50 grams, and a tool velocity of 5-30 mm/sec may be used. For profiling (e.g., flattening) a surface, the loading may be 100-175 grams, and the tool velocity may be 20-50 mm/sec. For imparting surface roughness, the tool loading may be in excess of 150 grams, and the tool velocity relative to the surface being processed may be 20-50 mm/sec.

**[0025]** The treatment tool may be provided in different sizes (diameter or effective diameter), depending on the size of the features or region on the work piece to be processed. For example, a smaller diameter treatment tool (for example, about 10 mm) may be used to treat recessed regions on a wafer chuck, such as the vacuum seal ring on a vacuum chuck.

**[0026]** According to a first aspect of the instant inventive method for mechanically finishing the support surface of a chuck, instead of a single treatment tool having a flat operating or processing surface, a plurality of such treatment tools are provided. At least two, and typically all of the tools of the plurality are used simultaneously. The tools process the support surface mechanically, that is, by removing material via abrasion. The tools may be moved as a group. Each tool is allowed to “float” on the surface, that is, to seek its own conformity with the surface. The pressure that each tool applies against the support surface may be controlled independently of the other tools in the plurality. The tool, or at least the flat surface of the tool, may be shaped as a ring or annulus. Tools may be arranged concentrically, that is, along a common

axis that is normal to the flat surface. Tools may also be arranged as a cluster, with no common axis that is normal to the flat surface. The processing of the support surface may be performed deterministically, that is, by programming the finishing to respond to a “hit” map of the elevation or roughness/smoothness of the support surface.

**[0027]** According to a second aspect of the invention, a treatment tool is used in a deterministic environment, with the treatment tool (i) being smaller in diameter or “effective diameter” than the diameter of the work piece (e.g., wafer chuck), and (ii) shaped as a toroid, or having a surface configured to physically contact the work piece that is ring or annulus-shaped.

**[0028]** According to a third aspect of the invention, a treatment tool is used in a deterministic environment, with the treatment tool having a surface configured to physically contact the work piece, with that contacting surface having a hardness that is about the same as the hardness of the work piece surface. In one embodiment, the treatment tool, or at least the flat contacting surface, is made from silicon carbide (SiC), or contains SiC, for example, in the form of a composite material such as reaction-bonded SiC.

**[0029]** In a deterministic setting or environment, the treatment tool is part of a machine. The machine receives data or information from an instrument such as an interferometer or profilometer. The data may be “figure” or elevation, or surface roughness information, expressed as a function of location on the surface of the chuck. This form of the data may be mathematically derived using the tool foot print or influence into a “hit map”, as it shows which locations are too high or too low or of the wrong surface roughness, and therefore it indicates to the machine which regions need to be processed by the

treatment tool. The machine may then instruct the treatment tool to process those regions necessary to achieve the desired figure and roughness. The hit map may permit the machine to ignore regions on the chuck that do not require attention, thereby saving time.

[0030] The invention embodiments will now be further described with specific reference to the attached drawings.

[0031] Referring first to Figure 1, what is shown is a plot of Power Spectral Density as a function of Spatial Frequency. Power Spectral Density is a measure of the amplitude of the deviations from the intended or desired elevation or profile of a surface. Spatial Frequency is a measure of the periodicity of these deviations; that is, how often do they occur in a given distance. What is plotted is elevation data for a surface before and after mechanical finishing treatment. That the “after” curve is below the “before” curve indicates that the deviations in elevation are being reduced; that is, the profile of the surface is closer to what is desired. In this case, flatness is desired, and the treatment shows that the work piece is getting flatter.

[0032] A lower power spectral density is desirable, which for this example, demonstrates that the part is getting flatter. The periods where the change occurred is nominally in and about 18 mm and smaller, corresponding to a spatial frequency of about 0.06 (cycle) per mm (or 0.06 1/mm).

[0033] Figures 2 and 3 are interferometer images that show these elevation deviations in gray scale as a function of location or position on the surface. Figure 2 shows the targeted spatial frequencies that need to be removed, that is,

reduced in elevation error. Figure 3 shows the same part as in Figure 2 with a low spatial frequency removed. That is, errors of a long periodicity or long wavelength (on the order of the diameter of the surface) have been removed; the overall flatness of the surface has been improved. This region is where some applications are the most sensitive.

[0034] Referring now to Figure 4, what is shown is a top view of a drawing showing concentric tools of different diameter, each independently configured with pressure to float over surface to fulfill a specific function, shape, flatten or roughen for example. Here, flattening will be performed before roughening, and will typically involve a greater amount of material being removed than does roughening. This illustration depicts the outer concentric tool 41 performing the flattening operation, and the inner concentric tool 43 performing the roughening operation.

[0035] Figure 5 depicts a top view of a drawing of a plurality of treatment tools 51, 53, 55, 57 arranged in non-concentric fashion. Here, the arrangement is termed a “cluster”, showing two or more tools that are non concentric performing independent actions of shaping of different spatial frequency ranges or texturing (roughening/smoothing). The cluster is mounted to a rotatable shaft  $\Theta$  (“theta”) that rotates on its longitudinal axis, termed the “theta” axis. Each tool is mounted to an axis 52, 54, 56, 58, which do not have to be parallel to one another, but are each attached to central axis  $\Theta$ . Rotation of the cluster allows the action to appear as one larger tool head moving along path 59 with a designed function by the sum of the independent members of the cluster. All tools are free to “float” (conformally) on the surface, for example, by being

minimally constrained in their attachment to their respective axes, for instance, by means of a ball-and-socket joint.

### EXAMPLE

[0036] The invention will now be further described with reference to the following Example.

#### **Example 1: Imparting Roughness Change**

[0037] This example demonstrates a localized roughness change, and is made with reference to Figures 6A and 6B.

[0038] Figure 6A is an optical photomicrograph of a ground and polished composite material flat surface prior to its treatment with a tool to deterministically roughen the surface. Both the treatment tool and the surface being processed have about the same hardness and each is fabricated from reaction bonded SiC (RBSC).

[0039] The treatment tool is 27 mm in diameter. By outward appearance, it is a disc, but in reality it has a slight toroidal shape so that when it is brought into contact with the flat surface, the area of contact is not that of a disc but instead is a circle or annulus. A dead weight loading of at least 150 grams is applied to the treatment tool. The tool is moved across the surface to be treated at a velocity in the range of 20-50 mm/sec.

[0040] Figure 6B is an optical photomicrograph of the same region of the ground and polished RBSC composite material flat surface of Figure 6A, but

following its treatment with the treatment tool operating in surface roughening mode. The three black arrows in each photomicrograph point to specific SiC grains. By comparing the appearance of the SiC grains near the tops of corresponding arrows, one can see changes in the grains. These changes are gouges or pits introduced into the grains as a result of the motion of the treatment tool over the flat surface.

[0041] Thus, this Example shows that the treatment tool of the instant invention can be used in a mode to impart localized surface roughness to a target surface being treated.

#### INDUSTRIAL APPLICABILITY

[0042] Although much of the forgoing discussion has focused on articles and devices for chucking semiconductor wafers, one of ordinary skill in the art will recognize other related applications where the techniques and articles disclosed in the instant patent application will be useful, for example, in other aspects of semiconductor wafer handling such as Vacuum Wafer Chucks, Wafer Arms, End Effectors, Retical Clamps and Susceptors.

[0043] What is proposed is to use mechanical techniques to flatten one or more narrow band of spatial frequencies using one or more tools, which may be annular or ring-shaped or toroidal. The ability to use several tools simultaneously allows for dramatic reduction in machining time.

[0044] Expanding a little further on this last point, in this aspect of the invention where multiple tools are used simultaneously, since the applied pressure on each tool can be independently controlled, and since pressure is highly relevant to the mode in which the tool operates, e.g., cleaning versus

profiling versus roughening, one tool can be loaded so as to perform in one mode, e.g., cleaning, while another tool is loaded to perform in a different mode, e.g., flattening or profiling. It may also be possible to differentiate modes of operation based upon velocity of the tool relative to the surface being treated. For example, in the embodiment in which treatment tools are arranged concentrically, if the tools are rotating with the same angular velocity, the outer tool will trace out a larger circumference than will the inner tool; thus, its surface velocity will be greater than that of the inner tool.

**[0045]** An artisan of ordinary skill will appreciate that various modifications may be made to the invention herein described without departing from the scope or spirit of the invention as defined in the appended claims.

## CLAIMS

What is claimed is:

1. A method for finishing the support surface of a chuck, comprising:
  - (a) providing a plurality of treatment tools each comprising a flat surface configured to contact and pass over said support surface;
  - (b) contacting said flat surface of each of said treatment tools to said support surface; and
  - (c) simultaneously moving at least two of said plurality of treatment tools at an applied pressure over at least a portion of said chuck support surface to be finished;
  - (d) wherein said applied pressure of each of said plurality against said support surface is independent of that of the others of said plurality, and controllable;
  - (e) and further wherein a diameter of said support surface is larger than an effective diameter of said plurality.
2. The method of claim 1, wherein each of said treatment tools are about the same size.
3. The method of claim 1, wherein at least one treatment tool has a different size relative to at least one other treatment tool.
4. The method of claim 1, wherein said contact area between each of said treatment tools and said support surface is shaped as a ring or an annulus.



5. The method of claim 1, wherein said plurality area arranged concentrically.

6. The method of claim 1, wherein said plurality are arranged along a common axis that is normal to said flat surface.

7. The method of claim 1, wherein said plurality are arranged as a cluster that do not share a common axis that is normal to said flat surface.

8. The method of claim 1, wherein said moving comprises removing material from said support surface to engineer an elevation of said support surface to a desired profile.

9. The method of claim 8, wherein said profile is flat.

10. The method of claim 1, wherein said moving comprises removing material from said support surface to engineer a desired roughness or smoothness of said support surface.

11. The method of claim 8 or claim 10, wherein said removing of material is performed deterministically.

12. A method for finishing the support surface of a chuck, comprising:  
(a) providing a machine comprising a treatment tool comprising a flat surface configured to contact and pass over said support surface, said treatment tool shaped as an annulus;

(b) providing information to said machine concerning one or more regions on the support surface that require correction;

(c ) physically or mechanically contacting said flat surface of said treatment tool to said support surface; and

(d) moving said treatment tool at an applied pressure over at least a portion of said chuck support surface to be finished, whereby said machine uses said inputted information to treat substantially only those regions of said support surface that require correction;

(e) and wherein a diameter of said support surface is larger than a diameter of said annulus.

13. The method of claim 12, wherein said treatment tool is shaped as a toroid.

14. The method of claim 12, wherein said treatment tool has about the same hardness as said support surface.

15. The method of claim 12, wherein said inputted information instructs said machine to correct a figure or elevation of said region.

16. The method of claim 12, wherein said inputted information instructs said machine to correct a texture of said region.

17. A method for finishing the support surface of a chuck, comprising:  
(a) providing a machine comprising a treatment tool comprising a flat surface configured to contact and pass over said support surface;  
(b) providing information to said machine concerning one or more regions on the support surface that require correction;

(c ) physically or mechanically contacting said flat surface of said treatment tool to said support surface; and

(d) moving said treatment tool at an applied pressure over at least a portion of said chuck support surface to be finished, whereby said machine responds deterministically to said inputted information to treat substantially only those regions of said support surface that require correction;

(e) and wherein said treatment tool has about the same hardness as said support surface.

18. The method of claim 17, wherein said flat surface configured to contact said support surface comprises SiC.

19. The method of claim 17, wherein said flat surface configured to contact said support surface comprises reaction-bonded SiC.

20. The method of claim 17, wherein said support surface has a larger diameter than said flat surface, and further wherein said treatment tool is shaped as an annulus.

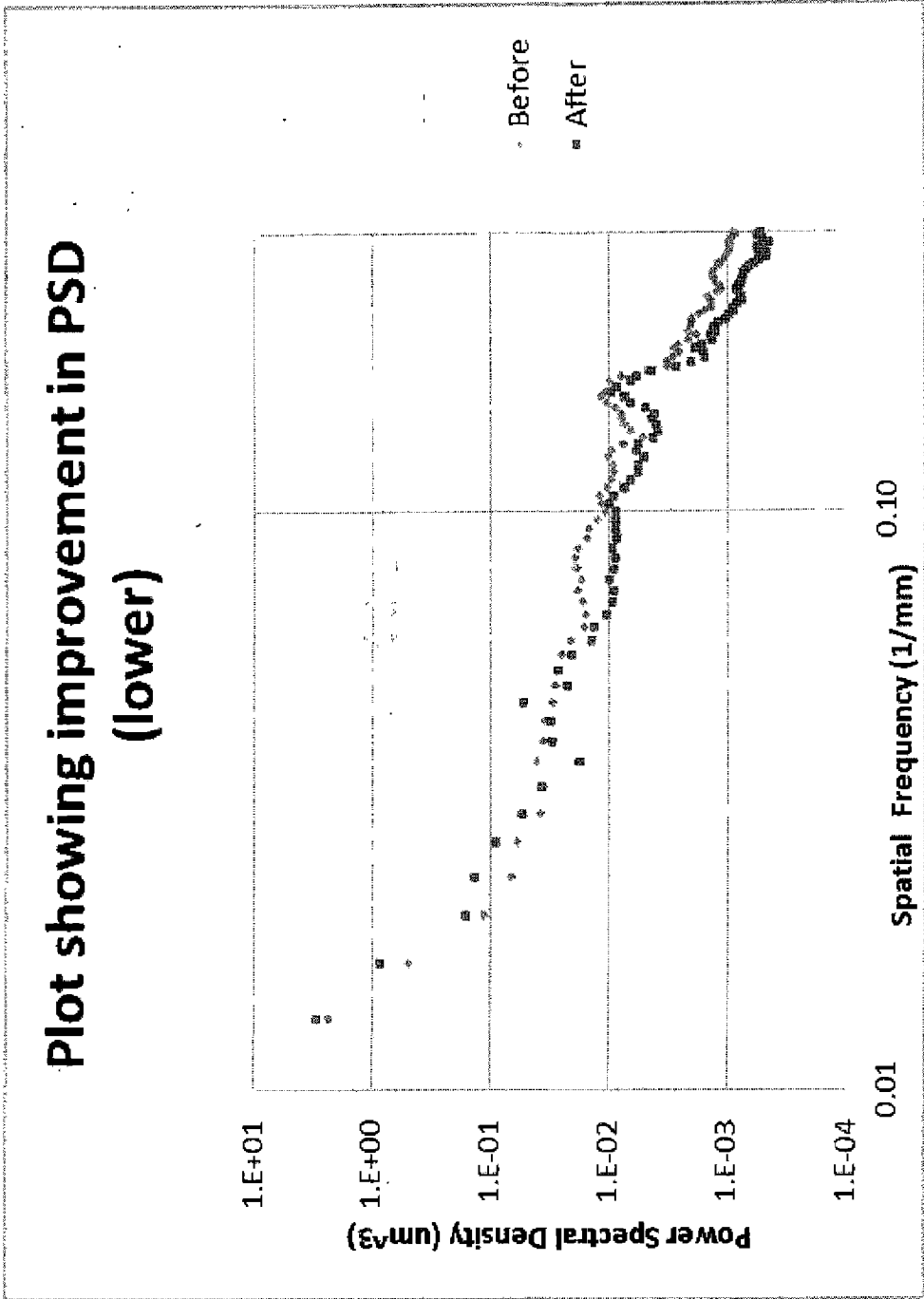


Fig. 1

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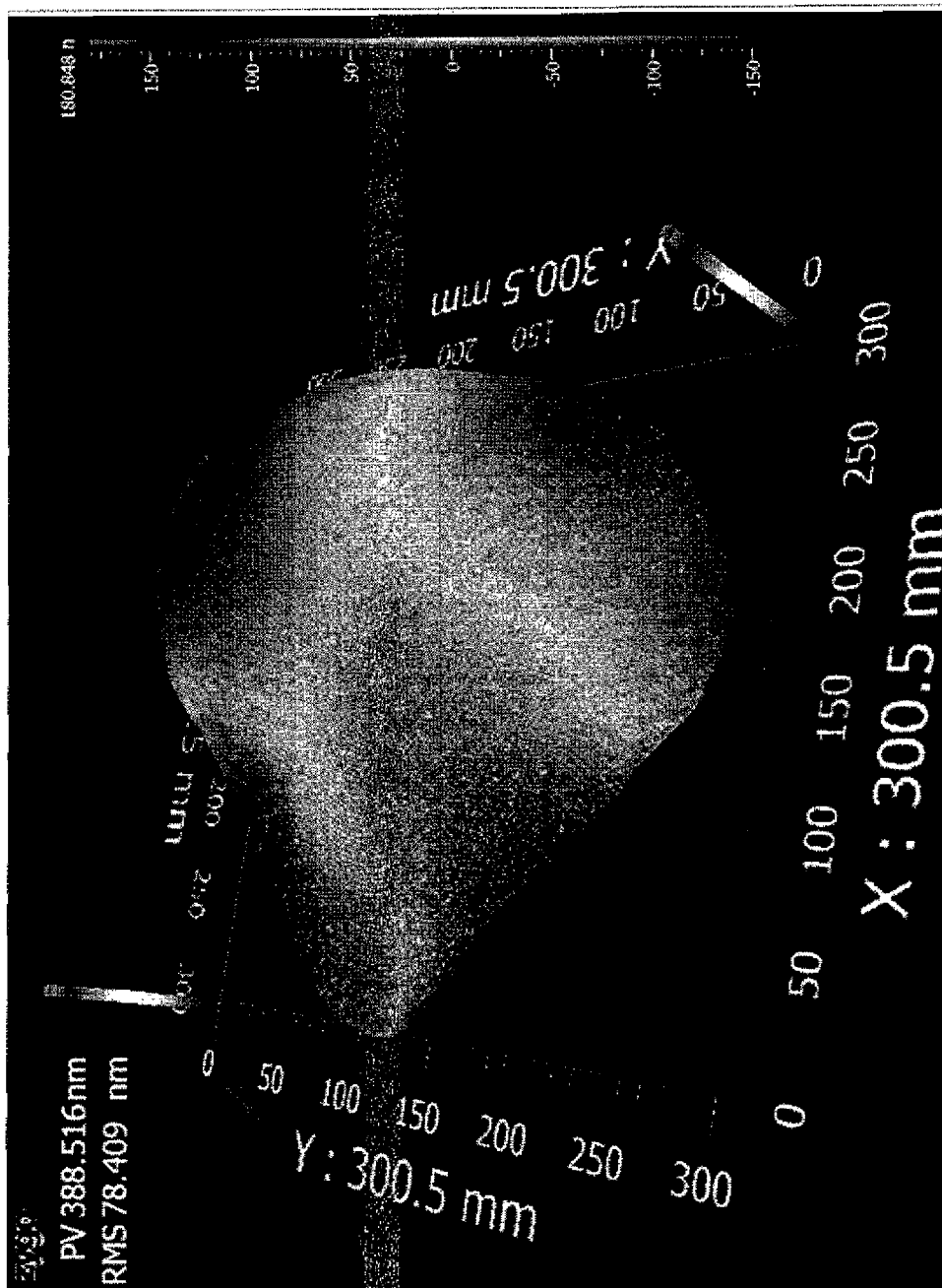


Fig. 2

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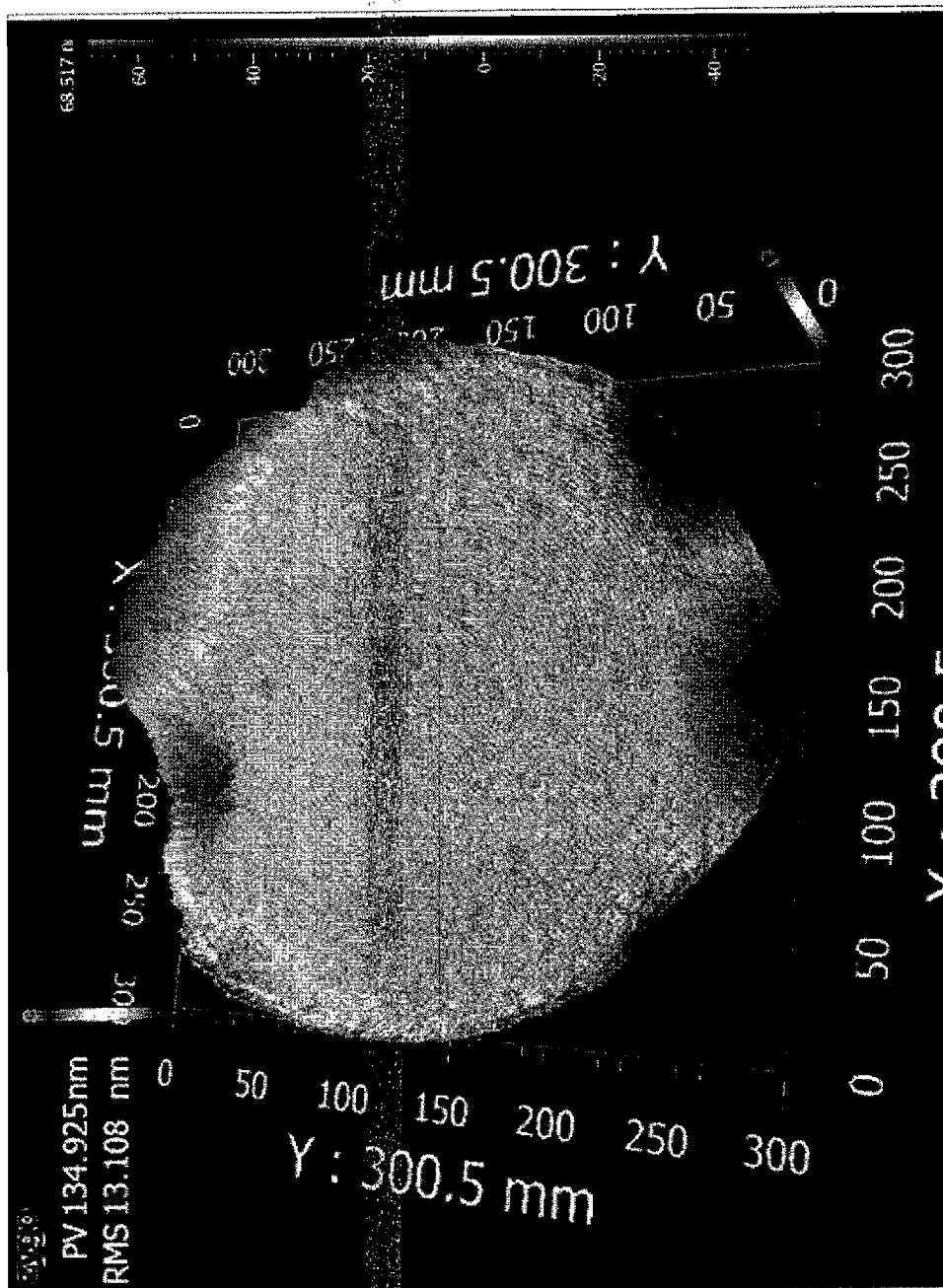


Fig. 3

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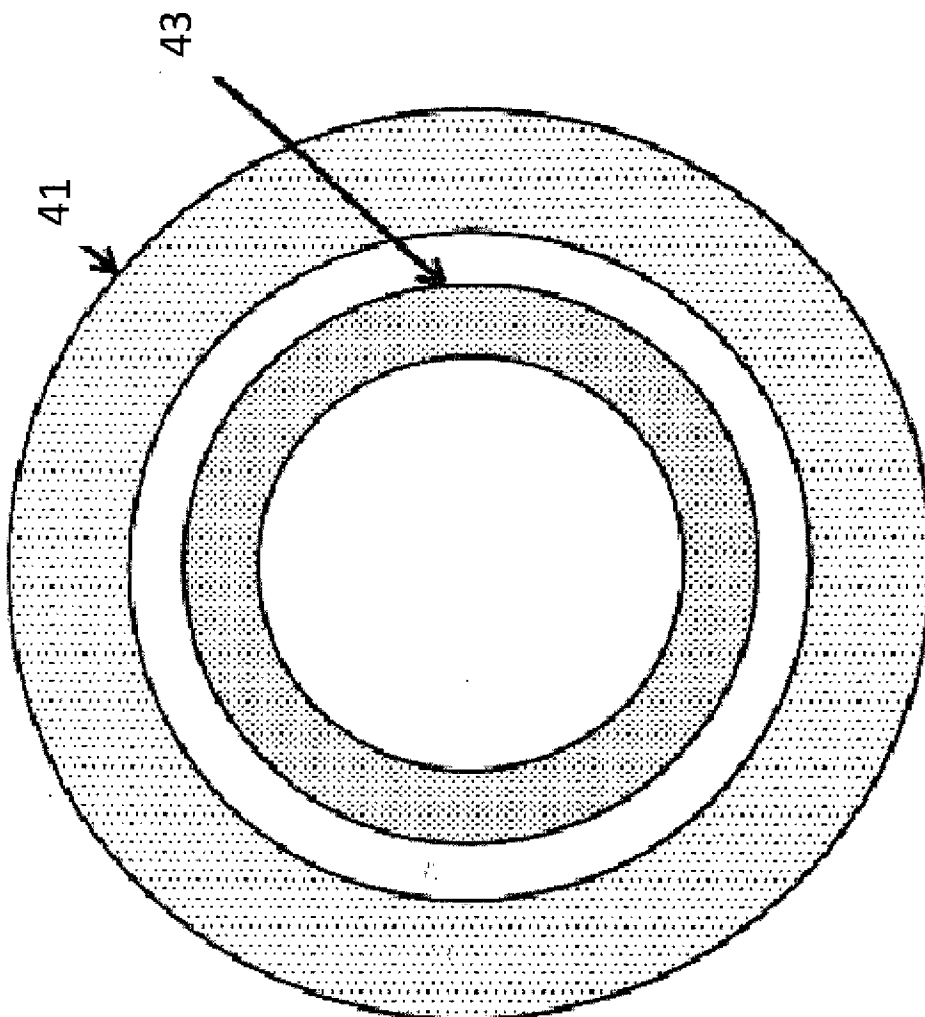


Fig. 4

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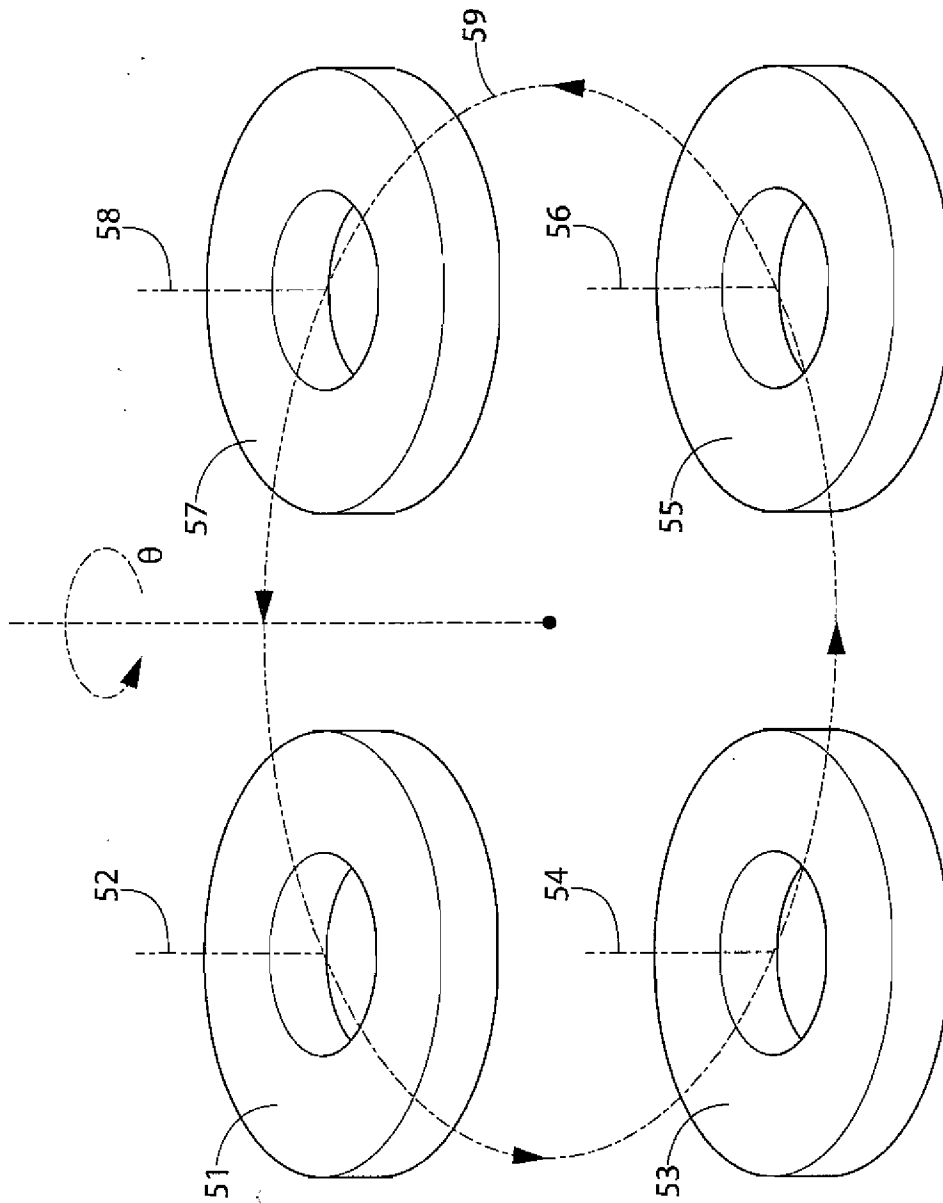


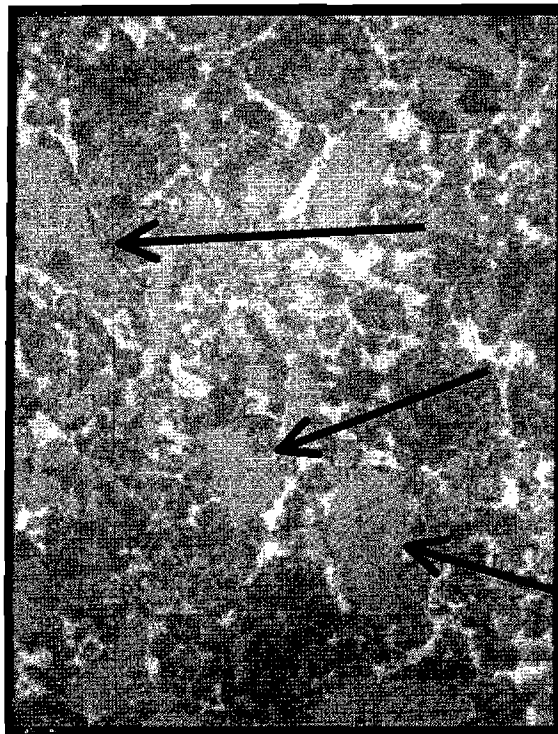
FIG. 5



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**Fig. 6B**



**Fig. 6A**